

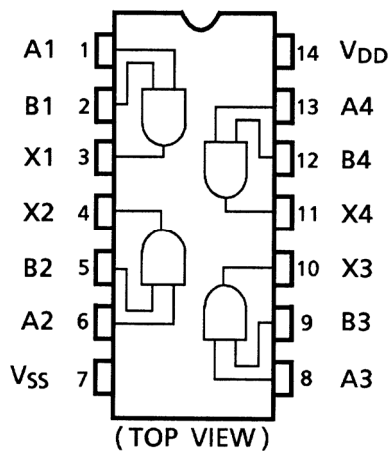
# TC4081BP, TC4081BF, TC4081BFN

## TC4081B Quad 2-Input AND Gate

TC4081B is positive logic AND gates with two inputs respectively.

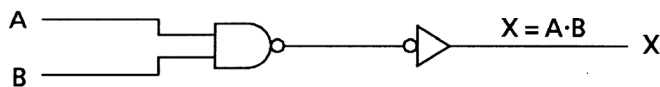
Since all the outputs of these gates are equipped with the buffer circuits of inverters, the input/output propagation characteristic has been improved and variation of propagation time caused by increase of load capacity is kept minimum.

### Pin Assignment



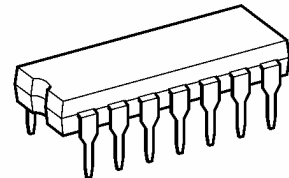
### Logic Diagram

#### 1/4 TC4081B



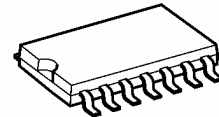
Note: xxxFN (JEDEC SOP) is not available in Japan.

TC4081BP

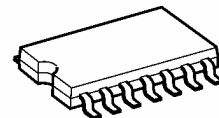


DIP14-P-300-2.54

TC4081BF

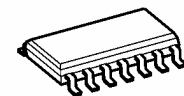


SOP14-P-300-1.27A



SOP14-P-300-1.27

TC4081BFN



SOL14-P-150-1.27

#### Weight

DIP14-P-300-2.54	: 0.96 g (typ.)
SOP14-P-300-1.27A	: 0.18 g (typ.)
SOP14-P-300-1.27	: 0.18 g (typ.)
SOL14-P-150-1.27	: 0.12 g (typ.)

**Absolute Maximum Ratings (Note)**

Characteristics	Symbol	Rating	Unit
DC supply voltage	$V_{DD}$	$V_{SS} - 0.5 \sim V_{SS} + 20$	V
Input voltage	$V_{IN}$	$V_{SS} - 0.5 \sim V_{DD} + 0.5$	V
Output voltage	$V_{OUT}$	$V_{SS} - 0.5 \sim V_{DD} + 0.5$	V
DC input current	$I_{IN}$	$\pm 10$	mA
Power dissipation	$P_D$	300 (DIP)/180 (SOIC)	mW
Operating temperature range	$T_{ope}$	$-40 \sim 85$	$^{\circ}\text{C}$
Storage temperature range	$T_{stg}$	$-65 \sim 150$	$^{\circ}\text{C}$

Note: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

**Recommended Operating Conditions ( $V_{SS} = 0 \text{ V}$ ) (Note)**

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
DC supply voltage	$V_{DD}$	—	3	—	18	V
Input voltage	$V_{IN}$	—	0	—	$V_{DD}$	V

Note: The recommended operating conditions are required to ensure the normal operation of the device. Unused inputs must be tied to either VCC or GND.

**Static Electrical Characteristics (V<sub>SS</sub> = 0 V)**

Characteristics	Sym- bol	Test Condition	V <sub>DD</sub> (V)	-40°C		25°C			85°C		Unit
				Min	Max	Min	Typ.	Max	Min	Max	
High-level output voltage	V <sub>OH</sub>	I <sub>OUT</sub>   < 1 μA V <sub>IN</sub> = V <sub>SS</sub> , V <sub>DD</sub>	5	4.95	—	4.95	5.00	—	4.95	—	V
			10	9.95	—	9.95	10.00	—	9.95	—	
			15	14.95	—	14.95	15.00	—	14.95	—	
Low-level output voltage	V <sub>OL</sub>	I <sub>OUT</sub>   < 1 μA V <sub>IN</sub> = V <sub>SS</sub> , V <sub>DD</sub>	5	—	0.05	—	0.00	0.05	—	0.05	V
			10	—	0.05	—	0.00	0.05	—	0.05	
			15	—	0.05	—	0.00	0.05	—	0.05	
Output high current	I <sub>OH</sub>	V <sub>OH</sub> = 4.6 V	5	-0.61	—	-0.51	-1.0	—	-0.42	—	mA
		V <sub>OH</sub> = 2.5 V	5	-2.50	—	-2.10	-4.0	—	-1.70	—	
		V <sub>OH</sub> = 9.5 V	10	-1.50	—	-1.30	-2.2	—	-1.10	—	
		V <sub>OH</sub> = 13.5 V	15	-4.00	—	-3.40	-9.0	—	-2.80	—	
		V <sub>IN</sub> = V <sub>DD</sub>									
Output low current	I <sub>OL</sub>	V <sub>OL</sub> = 0.4 V	5	0.61	—	0.51	1.2	—	0.42	—	mA
		V <sub>OL</sub> = 0.5 V	10	1.50	—	1.30	3.2	—	1.10	—	
		V <sub>OL</sub> = 1.5 V	15	4.00	—	3.40	12.0	—	2.80	—	
		V <sub>IN</sub> = V <sub>SS</sub> , V <sub>DD</sub>									
Input high voltage	V <sub>IH</sub>	V <sub>OUT</sub> = 0.5 V, 4.5 V	5	3.5	—	3.5	2.75	—	3.5	—	V
		V <sub>OUT</sub> = 1.0 V, 9.0 V	10	7.0	—	7.0	5.50	—	7.0	—	
		V <sub>OUT</sub> = 1.5 V, 13.5 V	15	11.0	—	11.0	8.25	—	11.0	—	
		I <sub>OUT</sub>   < 1 μA									
Input low voltage	V <sub>IL</sub>	V <sub>OUT</sub> = 0.5 V, 4.5 V	5	—	1.5	—	2.25	1.5	—	1.5	V
		V <sub>OUT</sub> = 1.0 V, 9.0 V	10	—	3.0	—	4.50	3.0	—	3.0	
		V <sub>OUT</sub> = 1.5 V, 13.5 V	15	—	4.0	—	6.75	4.0	—	4.0	
		I <sub>OUT</sub>   < 1 μA									
Input current	"H" level	I <sub>IH</sub>	V <sub>IH</sub> = 18 V	18	—	0.1	—	10 <sup>-5</sup>	0.1	—	μA
	"L" level	I <sub>IL</sub>	V <sub>IL</sub> = 0 V	18	—	-0.1	—	-10 <sup>-5</sup>	-0.1	—	
Quiescent supply current	I <sub>DD</sub>	V <sub>IN</sub> = V <sub>SS</sub> , V <sub>DD</sub> (Note)	5	—	0.25	—	0.001	0.25	—	7.5	μA
			10	—	0.50	—	0.001	0.50	—	15.0	
			15	—	1.00	—	0.002	1.00	—	30.0	

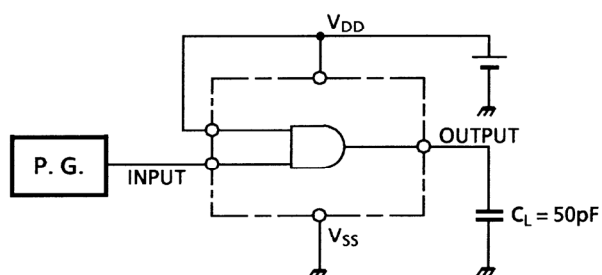
Note: All valid input combinations.

## Dynamic Electrical Characteristics (Ta = 25°C, V<sub>SS</sub> = 0 V, C<sub>L</sub> = 50 pF)

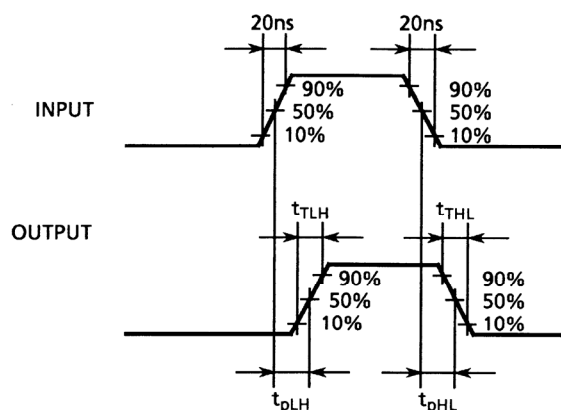
Characteristics	Symbol	Test Condition	V <sub>DD</sub> (V)	Min	Typ.	Max	Unit
Output transition time (low to high)	t <sub>TLH</sub>	—	5	—	70	200	ns
			10	—	35	100	
			15	—	30	80	
Output transition time (high to low)	t <sub>THL</sub>	—	5	—	70	200	ns
			10	—	35	100	
			15	—	30	80	
Propagation delay time	t <sub>pLH</sub>	—	5	—	65	200	ns
			10	—	30	100	
			15	—	25	80	
Propagation delay time	t <sub>pHL</sub>	—	5	—	65	200	ns
			10	—	30	100	
			15	—	25	80	
Input capacitance	C <sub>IN</sub>	—	—	—	5	7.5	pF

## Circuit and Waveform for Measurement of Dynamic Characteristics

### Circuit



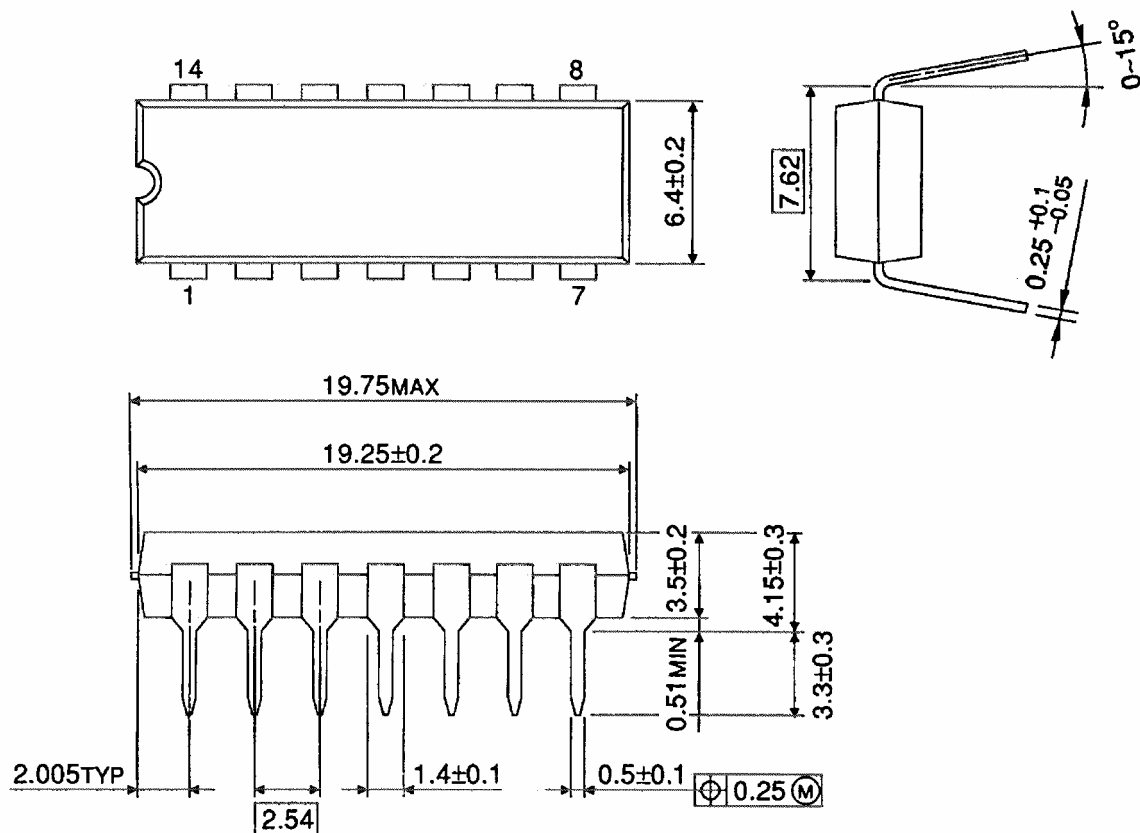
### Waveform



## Package Dimensions

DIP14-P-300-2.54

Unit : mm

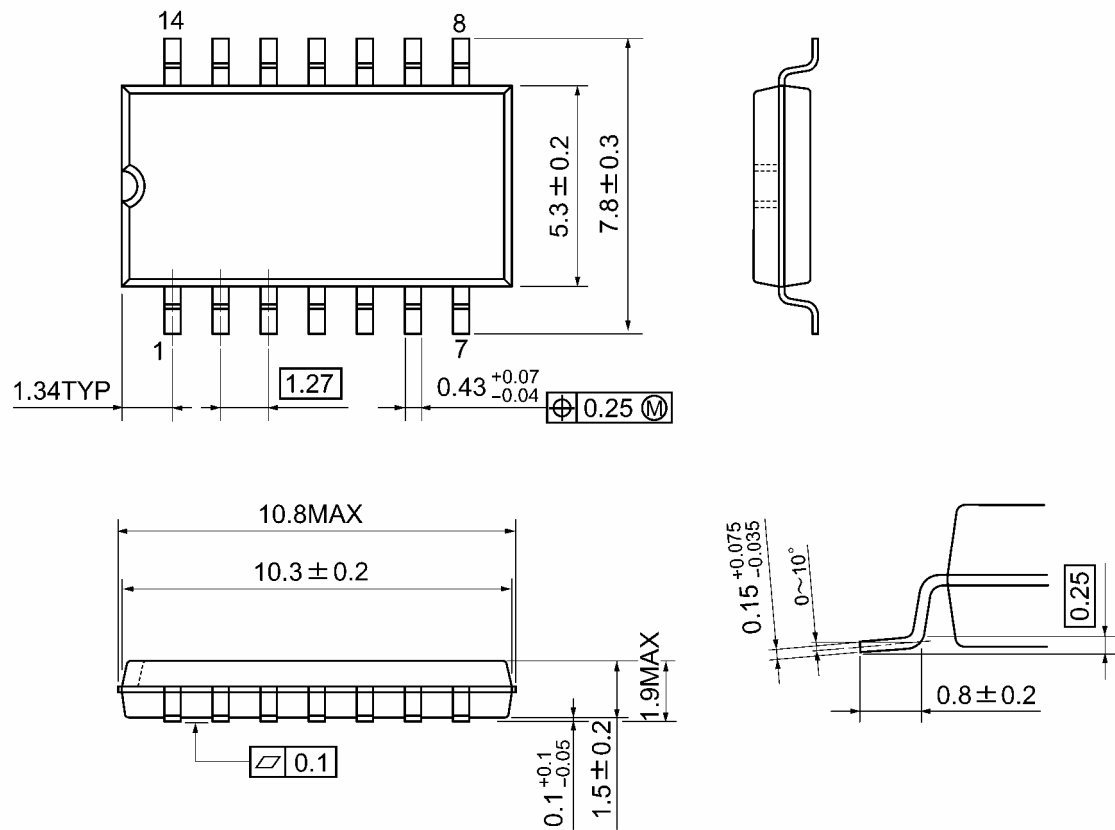


Weight: 0.96 g (typ.)

## Package Dimensions

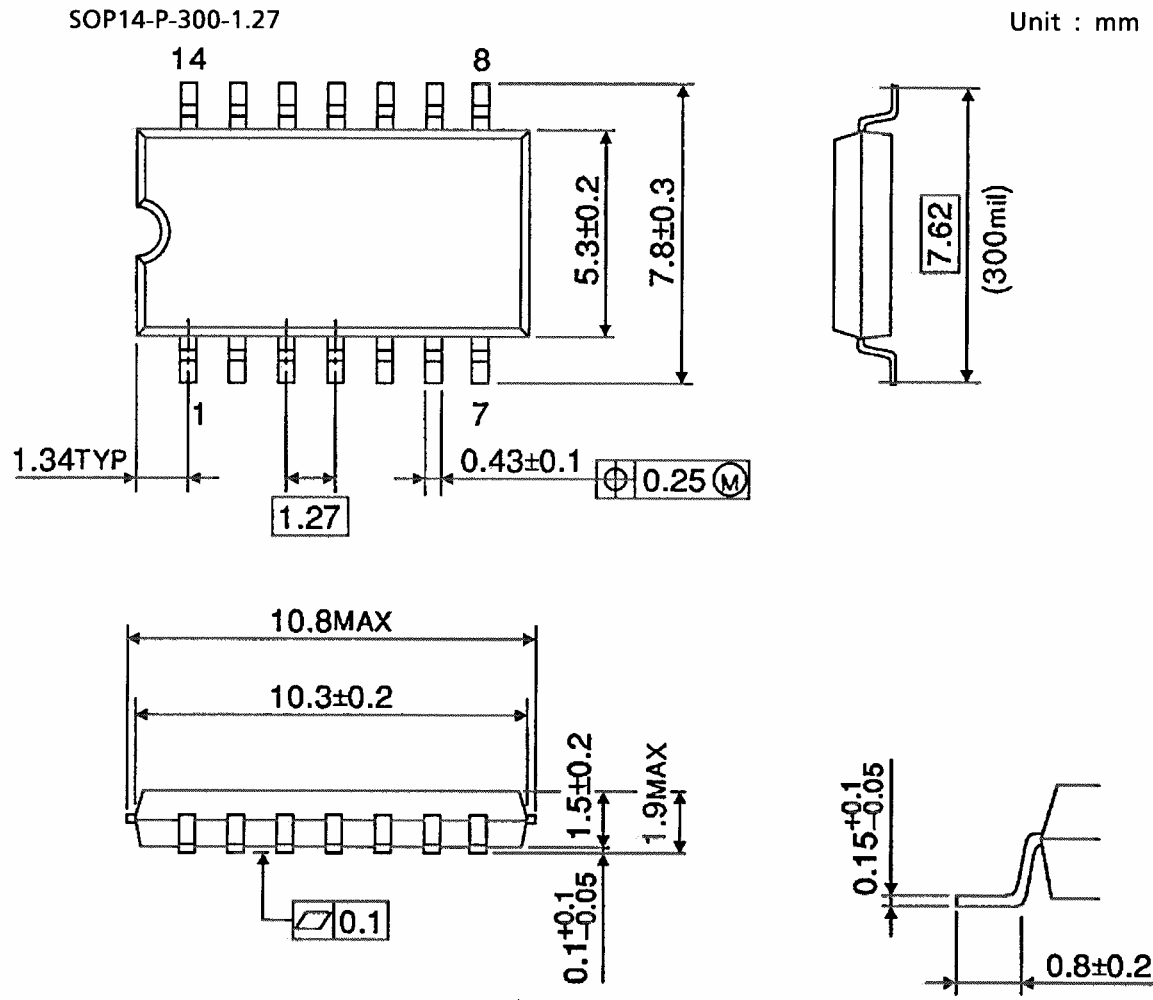
SOP14-P-300-1.27A

Unit: mm



Weight: 0.18 g (typ.)

Package Dimensions

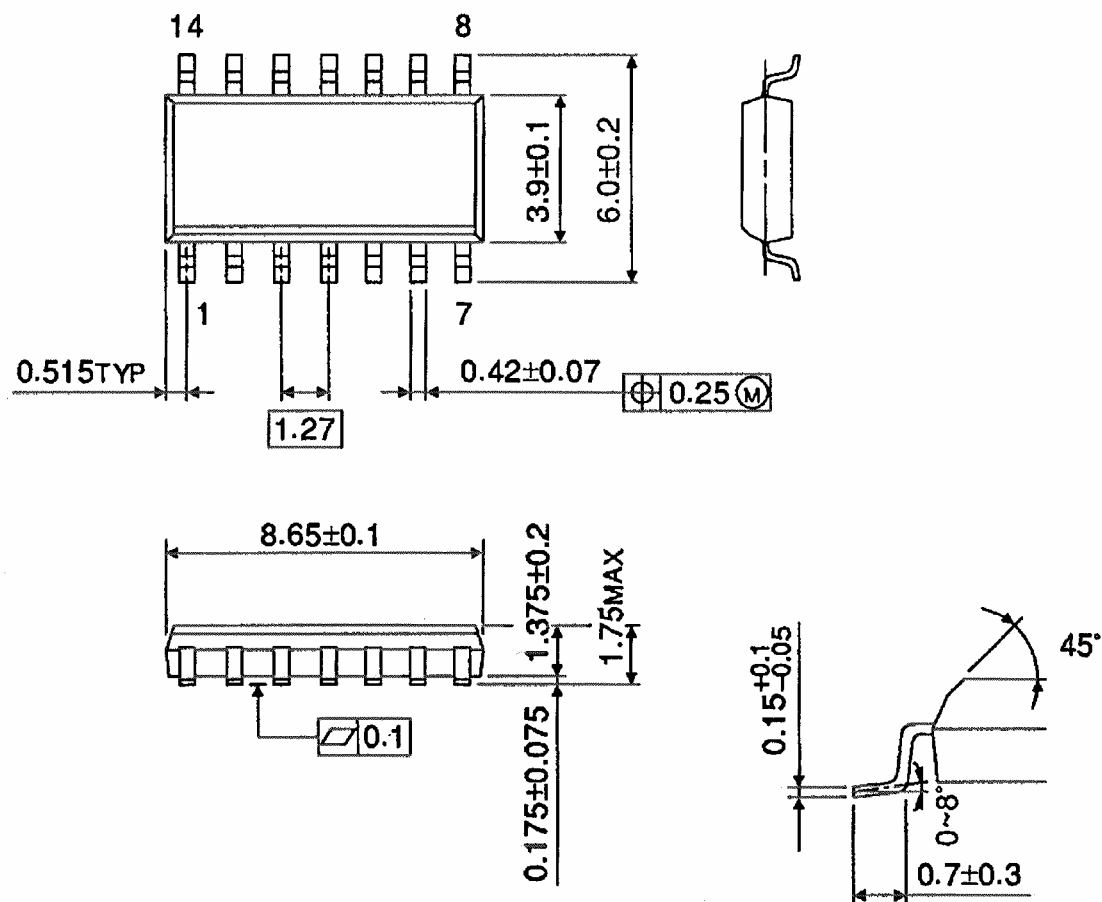


Weight: 0.18 g (typ.)

## Package Dimensions (Note)

SOL14-P-150-1.27

Unit : mm



Note: This package is not available in Japan.

Weight: 0.12 g (typ.)



**Note: Lead (Pb)-Free Packages****DIP14-P-300-2.54   SOP14-P-300-1.27A   SOL14-P-150-1.27****RESTRICTIONS ON PRODUCT USE**

20070701-EN

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